1. General description

NPN high power bipolar transistor in a power SOT428 Surface-Mounted Device (SMD) plastic package.

PNP complement: MJD32CA

2. Features and benefits

- · High thermal power dissipation capability
- · High energy efficiency due to less heat generation
- · Electrically similar to popular MJD31 series
- · Low collector emitter saturation voltage
- Fast switching speeds
- AEC-Q101 qualified

3. Applications

- · Power management
- Load switch
- Linear mode voltage regulator
- Constant current drive backlighting application
- Motor drive
- · Relay replacement

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	100	V
I _C	collector current		-	-	3	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	5	Α
h _{FE}	DC current gain	V _{CE} = 4 V; I _C = 1 A; T _{amb} = 25 °C	25	-	-	
		V _{CE} = 4 V; I _C = 3 A; T _{amb} = 25 °C	10	-	50	



100 V, 3 A NPN high power bipolar transistor

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	mb	Ę
2	С	collector		в - [**
3	Е	emitter		C; mb
mb	С	mounting base; connected to collector	DPAK (SOT428)	aaa-029889

6. Ordering information

Table 3. Ordering information

Type number			
	Name	Description	Version
MJD31CA		plastic, single-ended surface-mounted package (DPAK); 3 leads; 2.285 mm pitch; 6 mm x 6.6 mm x 2.3 mm body	SOT428

7. Marking

Table 4. Marking codes

Type number	Marking code
MJD31CA	MJD31CA

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC601134).

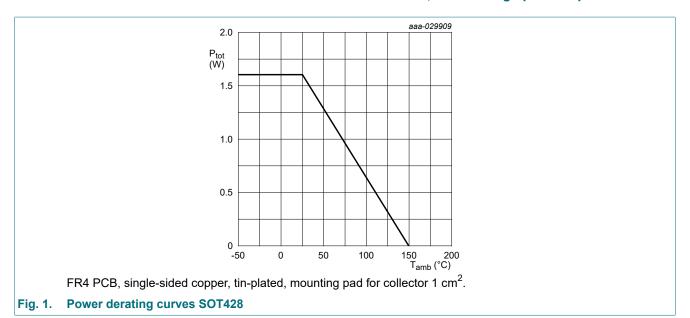
Symbol	Parameter	Conditions		Min	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	100	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	3	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	5	А
P _{tot}	total power dissipation	T _{mb} ≤ 25 °C	[1]	-	15	W
		T _{amb} ≤ 25 °C	[2]	-	1.6	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Total power dissipation junction to mounting base.

MJD31CA

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated mounting pad for collector 1 cm².

100 V, 3 A NPN high power bipolar transistor

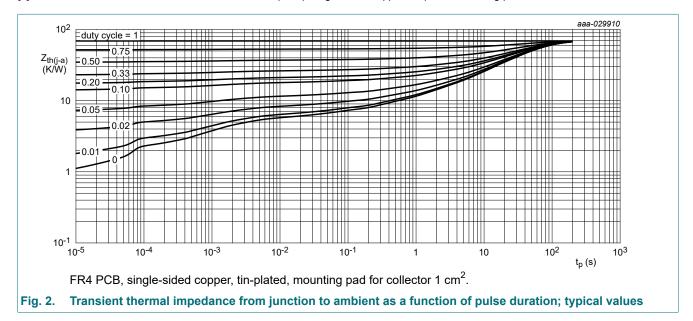


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	in free air		-	-	9	K/W
R _{th(j-a)}	thermal resistance from junction to ambient		[1]	-	-	79	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated mounting pad for collector 1 cm².



100 V, 3 A NPN high power bipolar transistor

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CES}	collector-emitter cut-off	V _{CE} = 80 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	1	μΑ
	current	V _{CE} = 64 V; V _{BE} = 0 V; T _j = 150 °C	-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	1	μΑ
h _{FE}	DC current gain	V _{CE} = 4 V; I _C = 1 A; T _{amb} = 25 °C	25	-	-	
		V _{CE} = 4 V; I _C = 3 A; T _{amb} = 25 °C	10	-	50	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 3 \text{ A}; I_B = 375 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	-	1.2	V
V_{BE}	base-emitter voltage	V _{CE} = 4 V; I _C = 3 A; T _{amb} = 25 °C	-	-	1.8	V
h _{fe}	small-signal current gain	V_{CE} = 10 V; I_{C} = 500 mA; f = 1 Hz; T_{amb} = 25 °C	20	-	-	
f _T	transition frequency	V_{CE} = 10 V; I_{C} = 500 mA; f = 1 MHz; T_{amb} = 25 °C	3	-	-	MHz

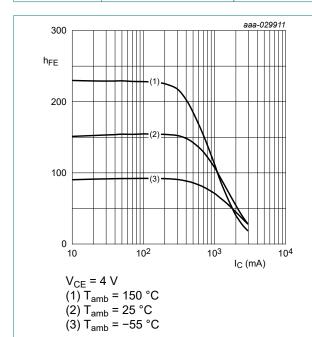


Fig. 3. DC current gain as a function of collector current; typical values

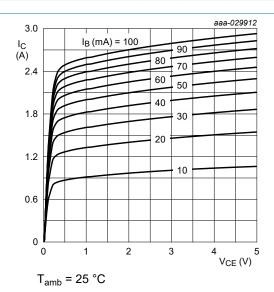
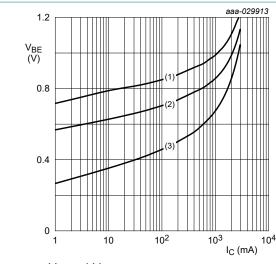


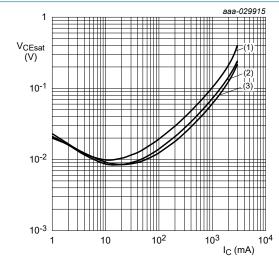
Fig. 4. Collector current as a function of collectoremitter voltage; typical values

100 V, 3 A NPN high power bipolar transistor



V_{CE} = 4 V (1) T_{amb} = -55 °C (2) T_{amb} = 25 °C (3) T_{amb} = 150 °C

Fig. 5. Base-emitter voltage as a function of collector current; typical values



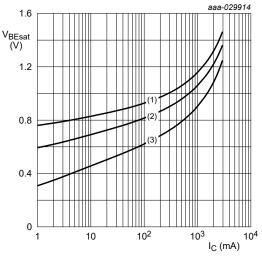
 $I_C/I_B = 10$

(1) T_{amb} = 150 °C

(2) $T_{amb} = 25 \, ^{\circ}C$

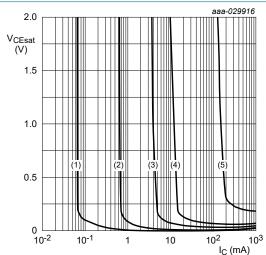
(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{C}/I_{B} = 10$ (1) $T_{amb} = -55 \,^{\circ}C$ (2) $T_{amb} = 25 \,^{\circ}C$ (3) $T_{amb} = 150 \,^{\circ}C$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



(1) $I_C = 10 \text{ mA}$

(2) $I_C = 100 \text{ mA}$

(3) $I_C = 500 \text{ mA}$

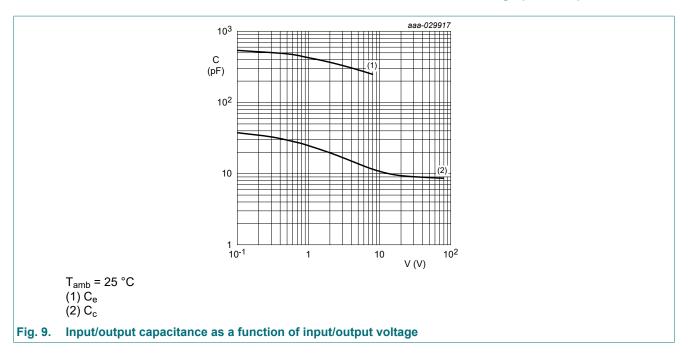
 $(4) I_C = 1000 \text{ mA}$

 $(5) I_C = 3000 \text{ mA}$

Fig. 8. Collector-emitter saturation region as a function of base current; typical values

5/11

100 V, 3 A NPN high power bipolar transistor



11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

6/11

100 V, 3 A NPN high power bipolar transistor

12. Package outline

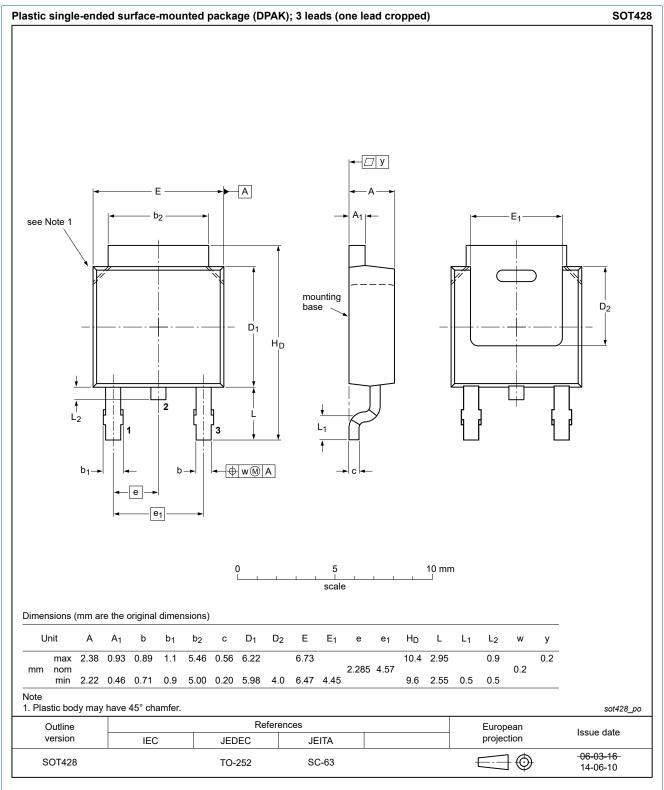
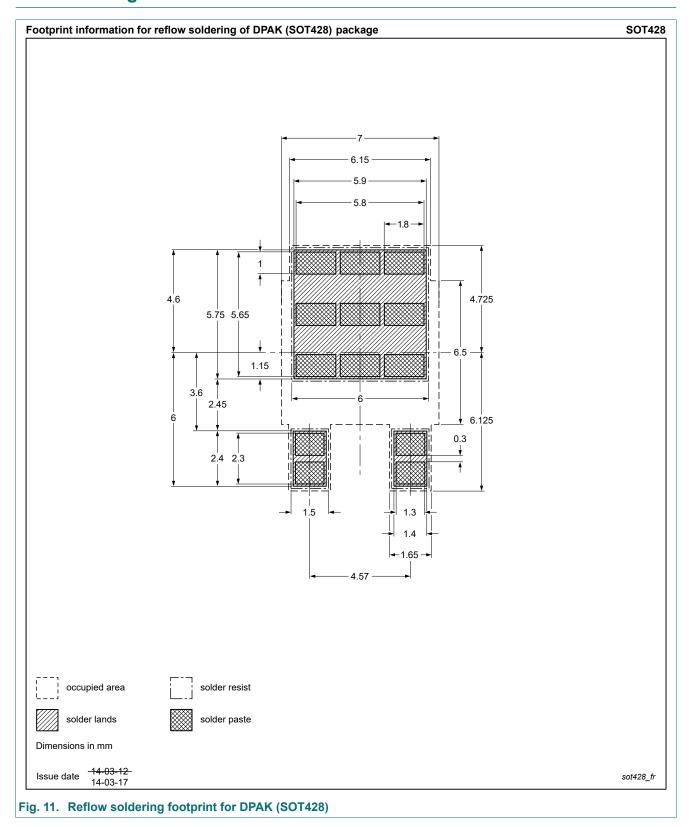


Fig. 10. Package outline DPAK (SOT428)

100 V, 3 A NPN high power bipolar transistor

13. Soldering



100 V, 3 A NPN high power bipolar transistor

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
MJD31CA v.1	20190523	Preliminary data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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MJD31CA

100 V, 3 A NPN high power bipolar transistor

Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	2
9. Thermal characteristics	3
10. Characteristics	4
11. Test information	6
12. Package outline	7
13. Soldering	
14. Revision history	
15. Legal information	

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